

FEATURES

- <1 pC charge injection over full signal range
- 1 pF off capacitance
- 33 V supply range
- 120 Ω on resistance
- Fully specified at $\pm 15\text{ V}/+12\text{ V}$
- 3 V logic compatible inputs
- Rail-to-rail operation
- Break-before-make switching action
- Available in 16-lead TSSOP, 4 mm \times 4 mm LFCSP_VQ, and 16-lead SOIC
- Typical power consumption < 0.03 μW

APPLICATIONS

- Audio and video routing
- Automatic test equipment
- Data-acquisition systems
- Battery-powered systems
- Sample-and-hold systems
- Communication systems

GENERAL DESCRIPTION

The ADG1208 and ADG1209 are monolithic, *i*CMOS[®] analog multiplexers comprising eight single channels and four differential channels, respectively. The ADG1208 switches one of eight inputs to a common output as determined by the 3-bit binary address lines A0, A1, and A2. The ADG1209 switches one of four differential inputs to a common differential output as determined by the 2-bit binary address lines A0 and A1. An EN input on both devices is used to enable or disable the device. When disabled, all channels are switched off. When on, each channel conducts equally well in both directions and has an input signal range that extends to the supplies.

The *i*CMOS (industrial CMOS) modular manufacturing process combines high voltage CMOS (complementary metal-oxide semiconductor) and bipolar technologies. It enables the development of a wide range of high performance analog ICs capable of 33 V operation in a footprint that no other generation of high voltage parts has been able to achieve. Unlike analog ICs using conventional CMOS processes, *i*CMOS components can tolerate high supply voltages while providing increased performance, dramatically lower power consumption, and reduced package size.

Rev. A

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FUNCTIONAL BLOCK DIAGRAMS

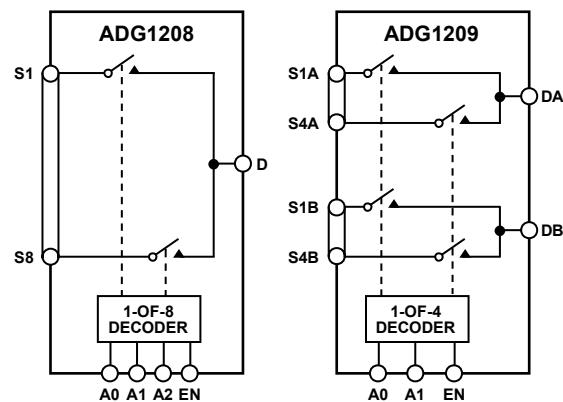
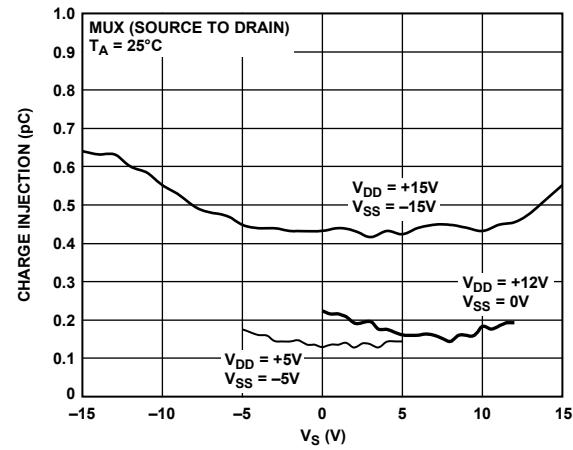


Figure 1.

05713-001

The ultralow capacitance and exceptionally low charge injection of these multiplexers make them ideal solutions for data acquisition and sample-and-hold applications, where low glitch and fast settling are required. Figure 2 shows that there is minimum charge injection over the entire signal range of the device. *i*CMOS construction also ensures ultralow power dissipation, making the parts ideally suited for portable and battery-powered instruments.



05713-001

Figure 2. Source to Drain Charge Injection vs. Source Voltage

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REVISION HISTORY

4/07—Rev. 0 to Rev. A

| | |
|--|-----------|
| Added 16-lead SOIC | Universal |
| Changes to Table 1 | 3 |
| Changes to Table 2 | 5 |
| Changes to Figure 10 and Figure 11 | 10 |
| Updated Outline Dimensions | 17 |
| Changes to Ordering Guide | 18 |

4/06—Revision 0: Initial Version

SPECIFICATIONS

DUAL SUPPLY

$V_{DD} = +15 \text{ V} \pm 10\%$, $V_{SS} = -15 \text{ V} \pm 10\%$, $\text{GND} = 0 \text{ V}$, unless otherwise noted.¹

Table 1.

| Parameter | +25°C | -40°C to +85°C | -40°C to +125°C | Unit | Test Conditions/Comments |
|---|-------------|----------------|-----------------|-------------------|---|
| ANALOG SWITCH | | | | | |
| Analog Signal Range | | | | V | |
| On Resistance, R_{ON} | 120 | | | Ω typ | $V_S = \pm 10 \text{ V}$, $I_S = -1 \text{ mA}$, see Figure 29 |
| | 200 | 240 | 270 | Ω max | $V_{DD} = +13.5 \text{ V}$, $V_{SS} = -13.5 \text{ V}$ |
| On Resistance Match Between Channels, ΔR_{ON} | 3.5 | | | Ω typ | $V_S = \pm 10 \text{ V}$, $I_S = -1 \text{ mA}$ |
| | 6 | 10 | 12 | Ω max | |
| On Resistance Flatness, R_{FLAT} (On) | 20 | | | Ω typ | $V_S = -5 \text{ V}/0 \text{ V}/+5 \text{ V}$, $I_S = -1 \text{ mA}$ |
| | 64 | 76 | 83 | Ω max | |
| LEAKAGE CURRENTS | | | | | |
| Source Off Leakage, I_S (Off) | ± 0.003 | | | nA typ | $V_D = \pm 10 \text{ V}$, $V_S = -10 \text{ V}$, see Figure 30 |
| | ± 0.1 | ± 0.6 | ± 1 | nA max | |
| Drain Off Leakage, I_D (Off) | ± 0.003 | | | nA typ | $V_S = 1 \text{ V}/10 \text{ V}$, $V_D = 10 \text{ V}/1 \text{ V}$, see Figure 30 |
| ADG1208 | ± 0.1 | ± 0.6 | ± 1 | nA max | |
| ADG1209 | ± 0.1 | ± 0.6 | ± 1 | nA max | |
| Channel On Leakage, I_D , I_S (On) | ± 0.02 | | | nA typ | $V_S = V_D = \pm 10 \text{ V}$, see Figure 31 |
| ADG1208 | ± 0.2 | ± 0.6 | ± 1 | nA max | |
| ADG1209 | ± 0.2 | ± 0.6 | ± 1 | nA max | |
| DIGITAL INPUTS | | | | | |
| Input High Voltage, V_{INH} | | 2.0 | | V min | |
| Input Low Voltage, V_{INL} | | 0.8 | | V max | |
| Input Current, I_{INL} or I_{INH} | ± 0.005 | | ± 0.1 | μA max | $V_{IN} = V_{INL}$ or V_{INH} |
| Digital Input Capacitance, C_{IN} | 2 | | | μA max | |
| | | | | pF typ | |
| DYNAMIC CHARACTERISTICS ² | | | | | |
| Transition Time, $t_{TRANSITION}$ | 80 | | | ns typ | $R_L = 300 \Omega$, $C_L = 35 \text{ pF}$ |
| | 130 | 165 | 185 | ns max | $V_S = 10 \text{ V}$, see Figure 32 |
| t_{ON} (EN) | 75 | | | ns typ | $R_L = 300 \Omega$, $C_L = 35 \text{ pF}$ |
| | 95 | 105 | 115 | ns max | $V_S = 10 \text{ V}$, see Figure 34 |
| t_{OFF} (EN) | 83 | | | ns typ | $R_L = 300 \Omega$, $C_L = 35 \text{ pF}$ |
| | 100 | 125 | 140 | ns max | $V_S = 10 \text{ V}$, see Figure 34 |
| Break-Before-Make Time Delay, t_{BBM} | 25 | | 10 | ns typ | $R_L = 300 \Omega$, $C_L = 35 \text{ pF}$ |
| | | | | ns min | $V_{S1} = V_{S2} = 10 \text{ V}$, see Figure 33 |
| Charge Injection | 0.4 | | | pC typ | $V_S = 0 \text{ V}$, $R_S = 0 \Omega$, $C_L = 1 \text{ nF}$, see Figure 35 |
| Off Isolation | -85 | | | dB typ | $R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, $f = 1 \text{ MHz}$, see Figure 36 |
| Channel-to-Channel Crosstalk | -85 | | | dB typ | $R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, $f = 1 \text{ MHz}$, see Figure 38 |
| Total Harmonic Distortion + Noise | 0.15 | | | % typ | $R_L = 10 \text{ k}\Omega$, 5 V rms, $f = 20 \text{ Hz}$ to 20 kHz , see Figure 39 |
| -3 dB Bandwidth | 550 | | | MHz typ | $R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, see Figure 37 |
| C_S (Off) | 1 | | | pF typ | $f = 1 \text{ MHz}$, $V_S = 0 \text{ V}$ |
| | 1.5 | | | pF max | $f = 1 \text{ MHz}$, $V_S = 0 \text{ V}$ |
| C_D (Off) ADG1208 | 6 | | | pF typ | $f = 1 \text{ MHz}$, $V_S = 0 \text{ V}$ |
| | 7 | | | pF max | $f = 1 \text{ MHz}$, $V_S = 0 \text{ V}$ |
| C_D (Off) ADG1209 | 3.5 | | | pF typ | $f = 1 \text{ MHz}$, $V_S = 0 \text{ V}$ |
| | 4.5 | | | pF max | $f = 1 \text{ MHz}$, $V_S = 0 \text{ V}$ |

ADG1208/ADG1209

| Parameter | +25°C | -40°C to +85°C | -40°C to +125°C | Unit | Test Conditions/Comments |
|--|--------|----------------|-----------------|------------------|--|
| C _D , C _S (On) ADG1208 | 7 8 | | | pF typ pF max | f = 1 MHz, V _S = 0 V f = 1 MHz, V _S = 0 V |
| C _D , C _S (On) ADG1209 | 5 6 | | | pF typ pF max | f = 1 MHz, V _S = 0 V f = 1 MHz, V _S = 0 V |
| POWER REQUIREMENTS | | | | | V _{DD} = +16.5 V, V _{SS} = -16.5 V |
| I _{DD} | 0.002 | | 1.0 | µA typ µA max | Digital inputs = 0 V or V _{DD} |
| I _{DD} | 220 | | 320 | µA typ µA max | Digital inputs = 5 V |
| I _{SS} | 0.002 | | 1.0 | µA typ µA max | Digital inputs = 0 V or V _{DD} |
| I _{SS} | 0.002 | | 1.0 ±5/±16.5 | µA typ µA max | Digital inputs = 5 V |
| V _{DD} /V _{SS} | | | | V min/max | V _{DD} = V _{SS} |

¹ Temperature range is as follows: Y version: -40°C to +125°C.

² Guaranteed by design, not subject to production test.

SINGLE SUPPLY

$V_{DD} = 12 \text{ V} \pm 10\%$, $V_{SS} = 0 \text{ V}$, GND = 0 V, unless otherwise noted.¹

Table 2.

| Parameter | +25°C | -40°C to +85°C | -40°C to +125°C | Unit | Test Conditions/Comments |
|---|-------------|----------------|-----------------|-------------------|---|
| ANALOG SWITCH | | | | | |
| Analog Signal Range | | | 0 to V_{DD} | V | |
| On Resistance, R_{ON} | 300 | | | Ω typ | $V_S = 0 \text{ V}$ to 10 V, $I_S = -1 \text{ mA}$, see Figure 29 |
| | 475 | 567 | 625 | Ω max | $V_{DD} = 10.8 \text{ V}$, $V_{SS} = 0 \text{ V}$ |
| On Resistance Match Between Channels, ΔR_{ON} | 5 | | | Ω typ | $V_S = 0 \text{ V}$ to 10 V, $I_S = -1 \text{ mA}$ |
| | 16 | 26 | 27 | Ω max | |
| On Resistance Flatness, R_{FLAT} (On) | 60 | | | Ω typ | $V_S = 3 \text{ V}/6 \text{ V}/9 \text{ V}$, $I_S = -1 \text{ mA}$ |
| LEAKAGE CURRENTS | | | | | |
| Source Off Leakage, I_S (Off) | ± 0.003 | | | nA typ | $V_{DD} = 13.2 \text{ V}$ |
| | ± 0.1 | ± 0.6 | ± 1 | nA max | $V_S = 1 \text{ V}/10 \text{ V}$, $V_D = 10 \text{ V}/1 \text{ V}$, see Figure 30 |
| Drain Off Leakage, I_D (Off) | ± 0.003 | | | nA typ | $V_S = 1 \text{ V}/10 \text{ V}$, $V_D = 10 \text{ V}/1 \text{ V}$, see Figure 30 |
| ADG1208 | ± 0.1 | ± 0.6 | ± 1 | nA max | |
| ADG1209 | ± 0.1 | ± 0.6 | ± 1 | nA max | |
| Channel On Leakage I_D , I_S (On) | ± 0.02 | | | nA typ | $V_S = V_D = 1 \text{ V}$ or 10 V, see Figure 31 |
| ADG1208 | ± 0.2 | ± 0.6 | ± 1 | nA max | |
| ADG1209 | ± 0.2 | ± 0.6 | ± 1 | nA max | |
| DIGITAL INPUTS | | | | | |
| Input High Voltage, V_{INH} | | | 2.0 | V min | |
| Input Low Voltage, V_{INL} | | | 0.8 | V max | |
| Input Current, I_{INL} or I_{INH} | ± 0.001 | | ± 0.1 | μA max | $V_{IN} = V_{INL}$ or V_{INH} |
| Digital Input Capacitance, C_{IN} | 3 | | | pF typ | |
| DYNAMIC CHARACTERISTICS ² | | | | | |
| Transition Time, $t_{TRANSITION}$ | 100 | | | ns typ | $R_L = 300 \Omega$, $C_L = 35 \text{ pF}$ |
| | 170 | 210 | 235 | ns typ | $V_S = 8 \text{ V}$, see Figure 32 |
| t_{ON} (EN) | 90 | | | ns typ | $R_L = 300 \Omega$, $C_L = 35 \text{ pF}$ |
| | 110 | 140 | 160 | ns typ | $V_S = 8 \text{ V}$, see Figure 34 |
| t_{OFF} (EN) | 105 | | | ns typ | $R_L = 300 \Omega$, $C_L = 35 \text{ pF}$ |
| | 130 | 155 | 175 | ns typ | $V_S = 8 \text{ V}$, see Figure 34 |
| Break-Before-Make Time Delay, t_{BBM} | 45 | | 20 | ns min | $R_L = 300 \Omega$, $C_L = 35 \text{ pF}$ |
| | | | | pC typ | $V_{S1} = V_{S2} = 8 \text{ V}$, see Figure 33 |
| Charge Injection | -0.2 | | | dB typ | $V_S = 6 \text{ V}$, $R_S = 0 \Omega$, $C_L = 1 \text{ nF}$, see Figure 35 |
| Off Isolation | -85 | | | dB typ | $R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, $f = 1 \text{ MHz}$, see Figure 36 |
| Channel-to-Channel Crosstalk | -85 | | | MHz typ | $R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, $f = 1 \text{ MHz}$, see Figure 38 |
| -3 dB Bandwidth | 450 | | | pF typ | $R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, see Figure 37 |
| C_S (Off) | 1.2 | | | pF max | $f = 1 \text{ MHz}$, $V_S = 6 \text{ V}$ |
| | 1.8 | | | pF typ | $f = 1 \text{ MHz}$, $V_S = 6 \text{ V}$ |
| C_D (Off) ADG1208 | 7.5 | | | pF typ | $f = 1 \text{ MHz}$, $V_S = 6 \text{ V}$ |
| | 9 | | | pF max | $f = 1 \text{ MHz}$, $V_S = 6 \text{ V}$ |
| C_D (Off) ADG1209 | 4.5 | | | pF typ | $f = 1 \text{ MHz}$, $V_S = 6 \text{ V}$ |
| | 5.5 | | | pF max | $f = 1 \text{ MHz}$, $V_S = 6 \text{ V}$ |
| C_D , C_S (On) ADG1208 | 9 | | | pF typ | $f = 1 \text{ MHz}$, $V_S = 6 \text{ V}$ |
| | 10.5 | | | pF max | $f = 1 \text{ MHz}$, $V_S = 6 \text{ V}$ |
| C_D , C_S (On) ADG1209 | 6 | | | pF typ | $f = 1 \text{ MHz}$, $V_S = 6 \text{ V}$ |
| | 7.5 | | | pF max | $f = 1 \text{ MHz}$, $V_S = 6 \text{ V}$ |

ADG1208/ADG1209

| Parameter | | +25°C | -40°C to +85°C | -40°C to +125°C | Unit | Test Conditions/Comments |
|--------------------|--|-------|----------------|-----------------|------------------|---|
| POWER REQUIREMENTS | | | | | | |
| I _{DD} | | 0.002 | | 1.0 | µA typ µA max | V _{DD} = 13.2 V Digital inputs = 0 V or V _{DD} |
| I _{DD} | | 220 | | 330 | µA typ µA max | Digital inputs = 5 V |
| V _{DD} | | | | 5/16.5 | V min/max | V _{SS} = 0 V, GND = 0 V |

¹ Temperature range is as follows: Y version: -40°C to +125°C.

² Guaranteed by design, not subject to production test.

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 3.

| Parameter | Rating |
|--|---|
| V_{DD} to V_{SS} | 35 V |
| V_{DD} to GND | -0.3 V to +25 V |
| V_{SS} to GND | +0.3 V to -25 V |
| Analog, Digital Inputs ¹ | $V_{SS} - 0.3 \text{ V}$ to $V_{DD} + 0.3 \text{ V}$ or 30 mA (whichever occurs first) |
| Continuous Current, S or D | 30 mA |
| Peak Current, S or D (Pulsed at 1 ms, 10% Duty Cycle Maximum) | 100 mA |
| Operating Temperature Range | |
| Industrial (Y Version) | -40°C to +125°C |
| Storage Temperature | -65°C to +150°C |
| Junction Temperature | 150°C |
| θ_{JA} , Thermal Impedance, TSSOP | 112°C/W |
| θ_{JA} , Thermal Impedance, LFCSP_VQ | 30.4°C/W |
| θ_{JA} , Thermal Impedance, SOIC_N | 77°C/W |
| Reflow Soldering Peak Temperature (Pb-Free) | 260(+0/-5)°C |

¹ Overvoltages at A, EN, S, or D are clamped by internal diodes. Current should be limited to the maximum ratings given.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

ADG1208/ADG1209

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

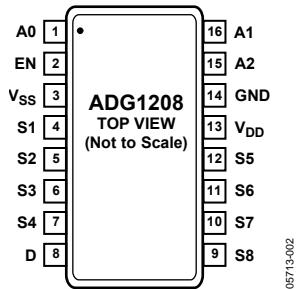


Figure 3. ADG1208 Pin Configuration (TSSOP/SOIC)

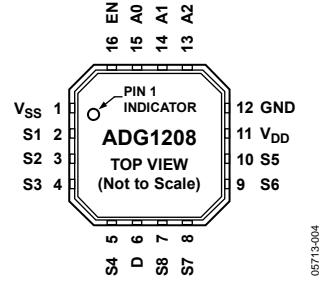


Figure 4. ADG1208 Pin Configuration (LFCSP_VQ), Exposed Pad Tied to Substrate, V_{SS}

Table 4. ADG1208 Pin Function Descriptions

| Pin Number | | Mnemonic | Description | |
|------------|----------|-----------------|---|--|
| TSSOP/SOIC | LFCSP_VQ | | | |
| 1 | 15 | A0 | Logic Control Input. | |
| 2 | 16 | EN | Active High Digital Input. When low, the device is disabled and all switches are off. When high, Ax logic inputs determine on switches. | |
| 3 | 1 | V _{SS} | Most Negative Power Supply Potential. In single-supply applications, it can be connected to ground. | |
| 4 | 2 | S1 | Source Terminal 1. Can be an input or an output. | |
| 5 | 3 | S2 | Source Terminal 2. Can be an input or an output. | |
| 6 | 4 | S3 | Source Terminal 3. Can be an input or an output. | |
| 7 | 5 | S4 | Source Terminal 4. Can be an input or an output. | |
| 8 | 6 | D | Drain Terminal. Can be an input or an output. | |
| 9 | 7 | S8 | Source Terminal 8. Can be an input or an output. | |
| 10 | 8 | S7 | Source Terminal 7. Can be an input or an output. | |
| 11 | 9 | S6 | Source Terminal 6. Can be an input or an output. | |
| 12 | 10 | S5 | Source Terminal 5. Can be an input or an output. | |
| 13 | 11 | V _{DD} | Most Positive Power Supply Potential. | |
| 14 | 12 | GND | Ground (0 V) Reference. | |
| 15 | 13 | A2 | Logic Control Input. | |
| 16 | 14 | A1 | Logic Control Input. | |

Table 5. ADG1208 Truth Table

| A2 | A1 | A0 | EN | On Switch |
|----|----|----|----|-----------|
| X | X | X | 0 | None |
| 0 | 0 | 0 | 1 | 1 |
| 0 | 0 | 1 | 1 | 2 |
| 0 | 1 | 0 | 1 | 3 |
| 0 | 1 | 1 | 1 | 4 |
| 1 | 0 | 0 | 1 | 5 |
| 1 | 0 | 1 | 1 | 6 |
| 1 | 1 | 0 | 1 | 7 |
| 1 | 1 | 1 | 1 | 8 |

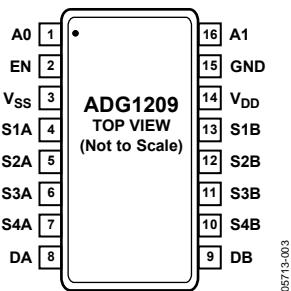


Figure 5. ADG1209 Pin Configuration (TSSOP/SOIC)

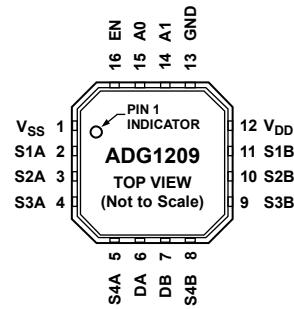
Figure 6. ADG1209 Pin Configurations (LFCSP_VQ), Exposed Pad Tied to Substrate, V_{ss}

Table 6. ADG1209 Pin Function Descriptions

| Pin Number | | Mnemonic | Description |
|------------|----------|----------|---|
| TSSOP/SOIC | LFCSP_VQ | | |
| 1 | 15 | A0 | Logic Control Input. |
| 2 | 16 | EN | Active High Digital Input. When low, the device is disabled and all switches are off. When high, Ax logic inputs determine on switches. |
| 3 | 1 | V_{ss} | Most Negative Power Supply Potential. In single-supply applications, it can be connected to ground. |
| 4 | 2 | S1A | Source Terminal 1A. Can be an input or an output. |
| 5 | 3 | S2A | Source Terminal 2A. Can be an input or an output. |
| 6 | 4 | S3A | Source Terminal 3A. Can be an input or an output. |
| 7 | 5 | S4A | Source Terminal 4A. Can be an input or an output. |
| 8 | 6 | DA | Drain Terminal A. Can be an input or an output. |
| 9 | 7 | DB | Drain Terminal B. Can be an input or an output. |
| 10 | 8 | S4B | Source Terminal 4B. Can be an input or an output. |
| 11 | 9 | S3B | Source Terminal 3B. Can be an input or an output. |
| 12 | 10 | S2B | Source Terminal 2B. Can be an input or an output. |
| 13 | 11 | S1B | Source Terminal 1B. Can be an input or an output. |
| 14 | 12 | V_{dd} | Most Positive Power Supply Potential. |
| 15 | 13 | GND | Ground (0 V) Reference. |
| 16 | 14 | A1 | Logic Control Input. |

Table 7. ADG1209 Truth Table

| A1 | A0 | EN | On Switch Pair |
|----|----|----|----------------|
| X | X | 0 | None |
| 0 | 0 | 1 | 1 |
| 0 | 1 | 1 | 2 |
| 1 | 0 | 1 | 3 |
| 1 | 1 | 1 | 4 |

ADG1208/ADG1209

TYPICAL PERFORMANCE CHARACTERISTICS

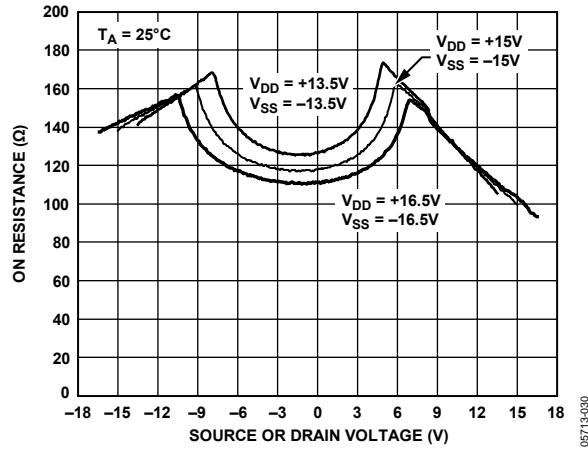


Figure 7. On Resistance as a Function of V_D (V_S) for Dual Supply

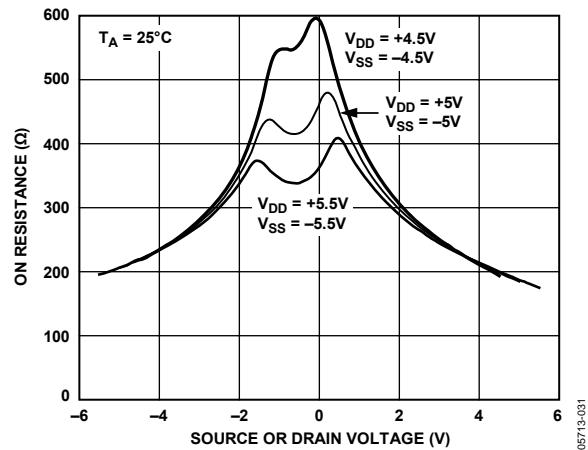


Figure 8. On Resistance as a Function of V_D (V_S) for Dual Supply

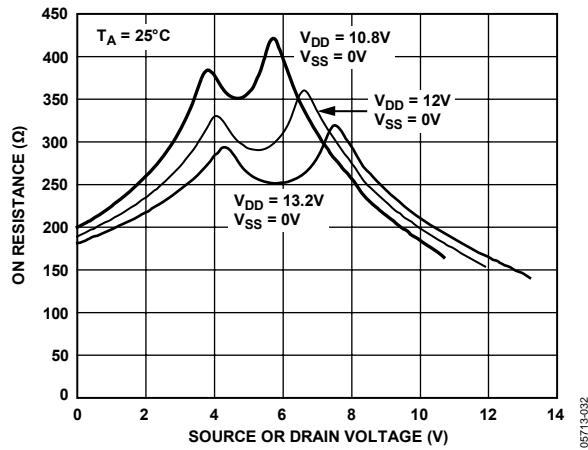


Figure 9. On Resistance as a Function of V_D (V_S) for Single Supply

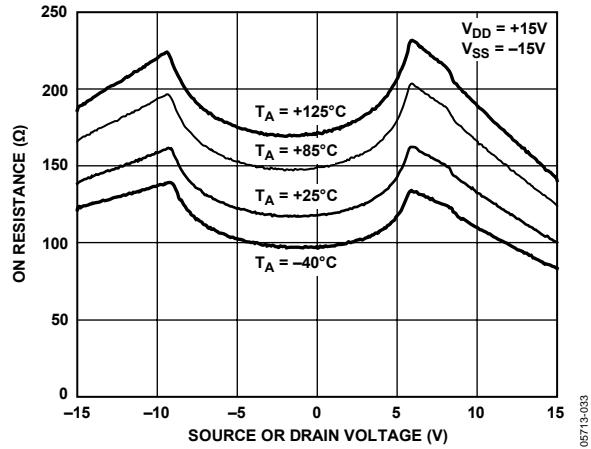


Figure 10. On Resistance as a Function of V_D (V_S) for Different Temperatures, Dual Supply

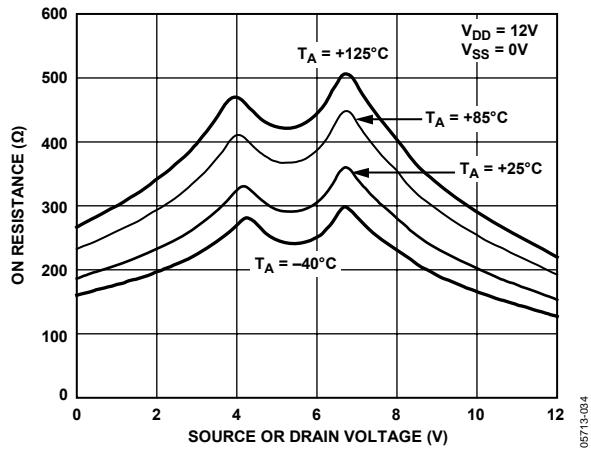


Figure 11. On Resistance as a Function of V_D (V_S) for Different Temperatures, Single Supply

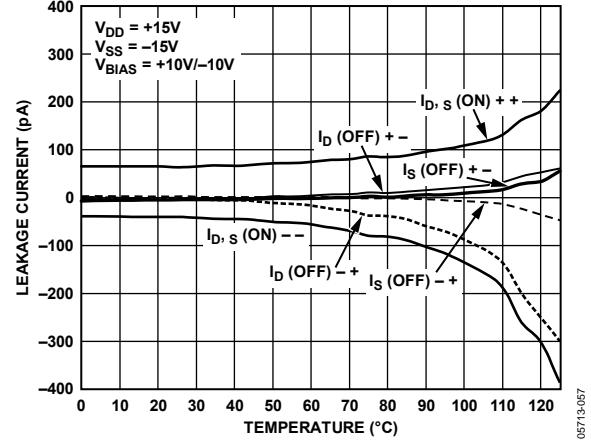
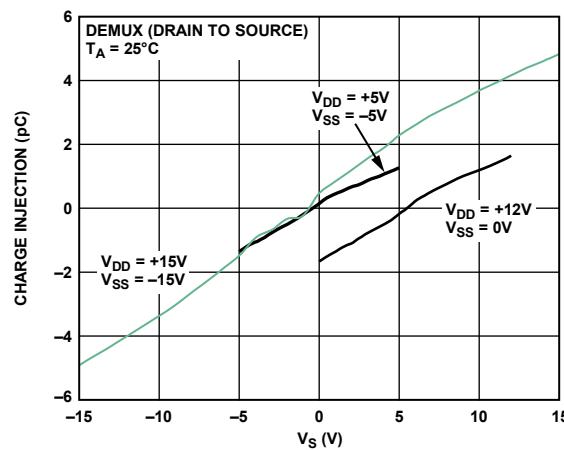
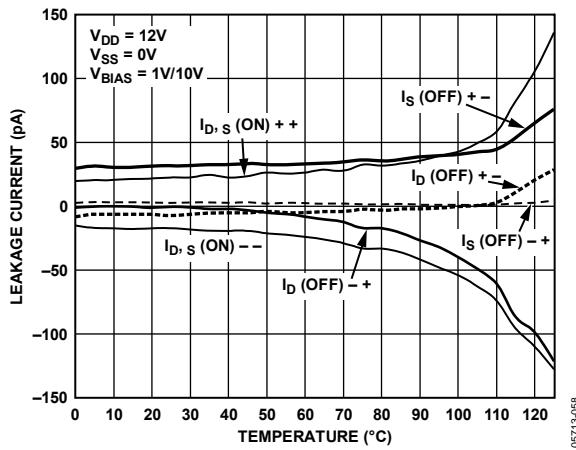
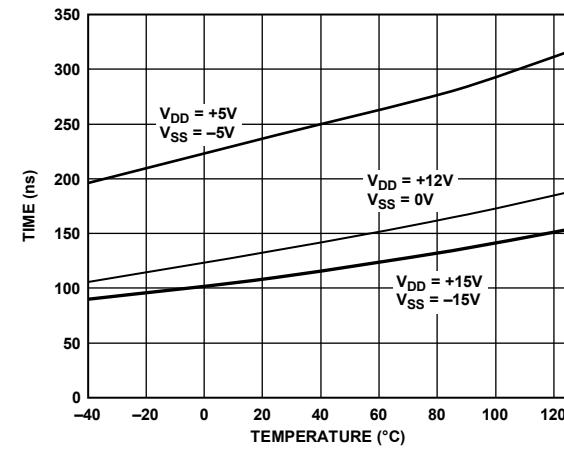
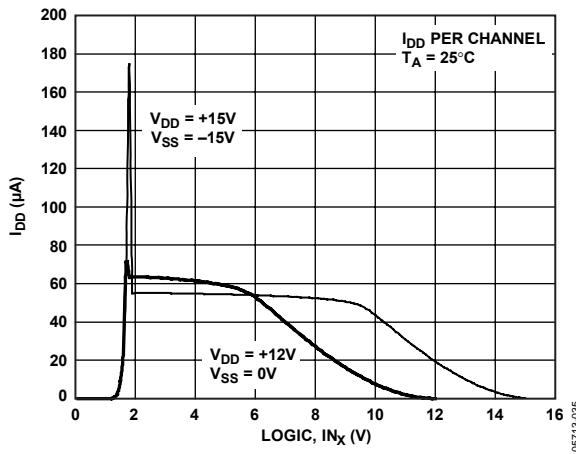


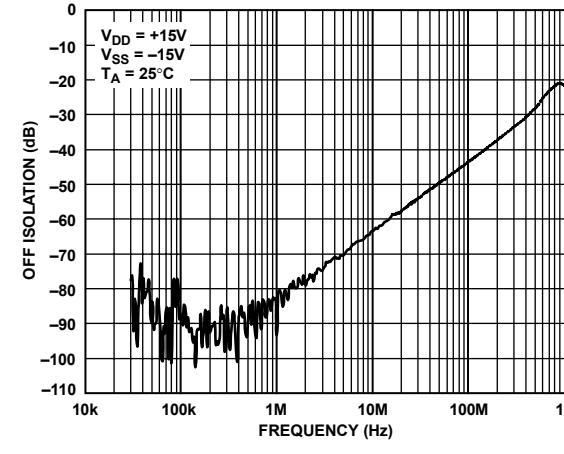
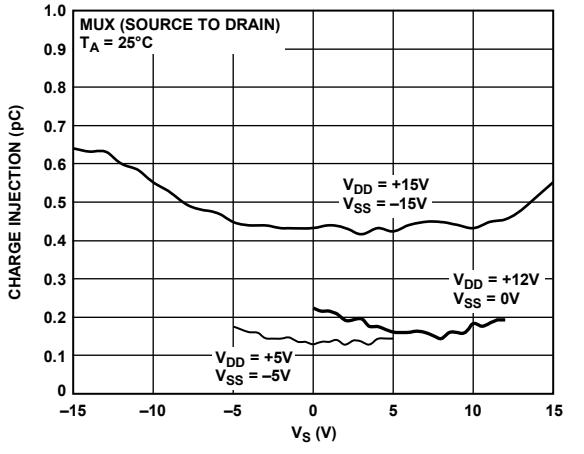
Figure 12. ADG1208 Leakage Currents as a Function of Temperature, Dual Supply



05713-041



05713-052



05713-049

ADG1208/ADG1209

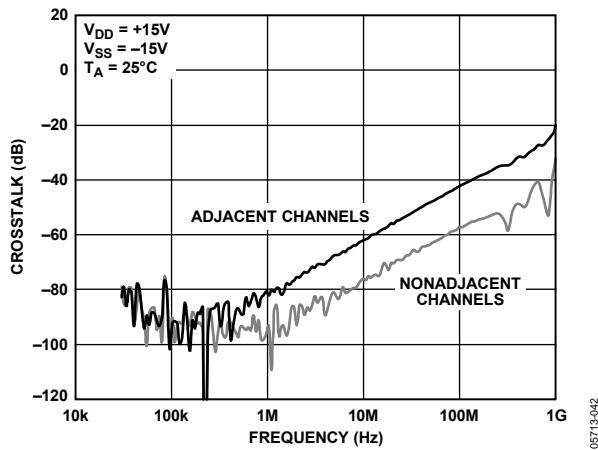


Figure 19. ADG1208 Crosstalk vs. Frequency

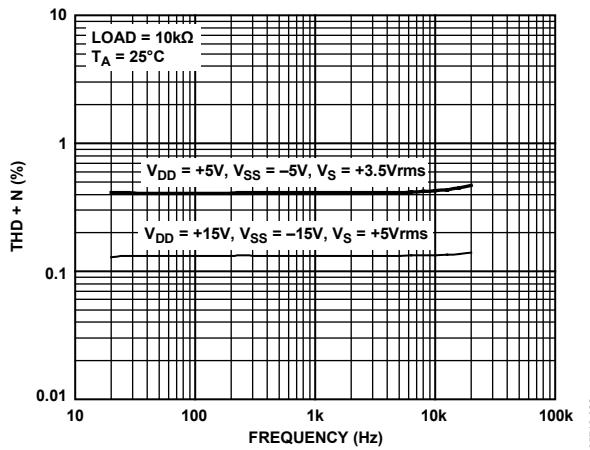


Figure 22. THD + N vs. Frequency

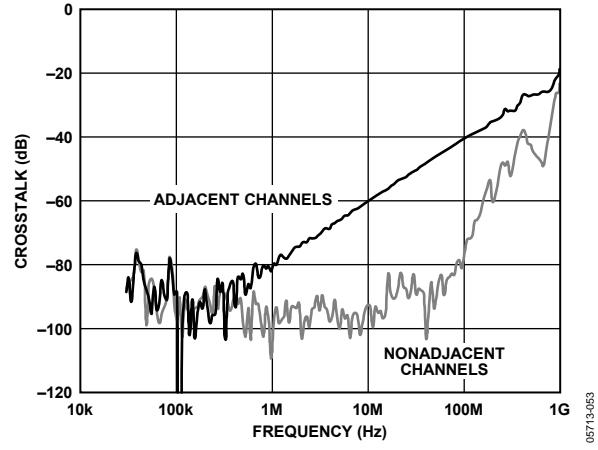


Figure 20. ADG1209 Crosstalk vs. Frequency

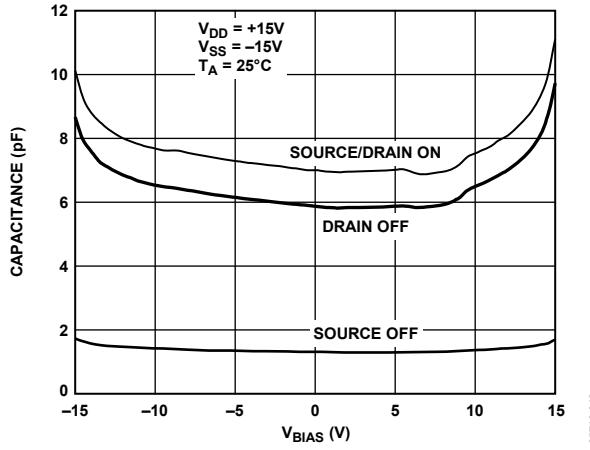


Figure 23. ADG1208 Capacitance vs. Source Voltage,
±15 V Dual Supply

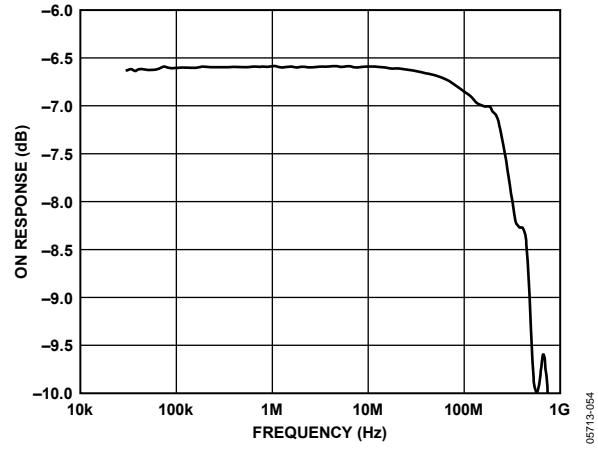


Figure 21. On Response vs. Frequency

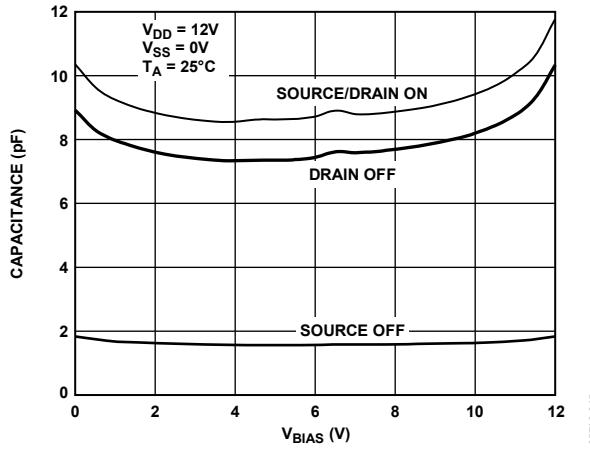


Figure 24. ADG1208 Capacitance vs. Source Voltage,
12 V Single Supply

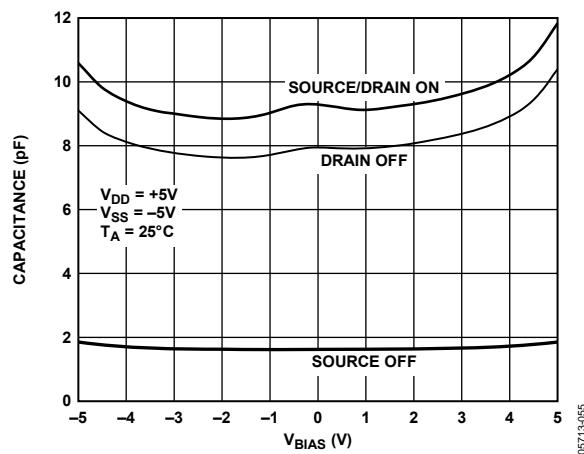


Figure 25. ADG1208 Capacitance vs. Source Voltage, ± 5 V Dual Supply

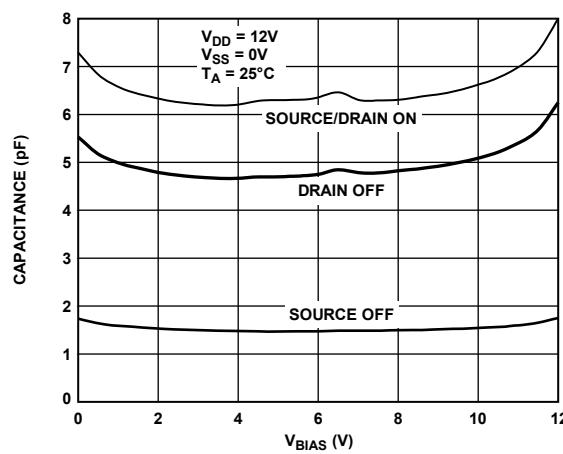


Figure 27. ADG1209 Capacitance vs. Source Voltage, 12 V Single Supply

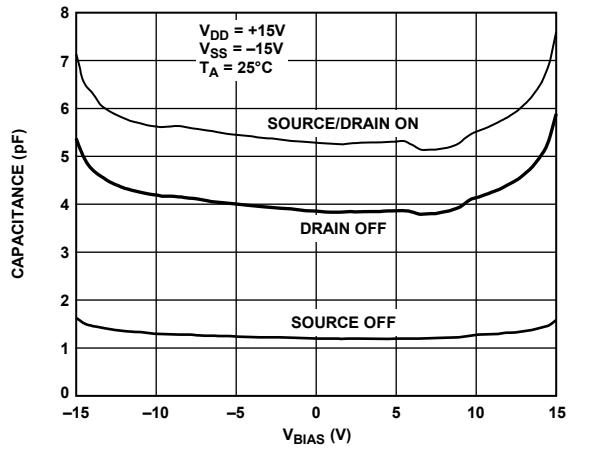


Figure 26. ADG1209 Capacitance vs. Source Voltage, ± 15 V Dual Supply

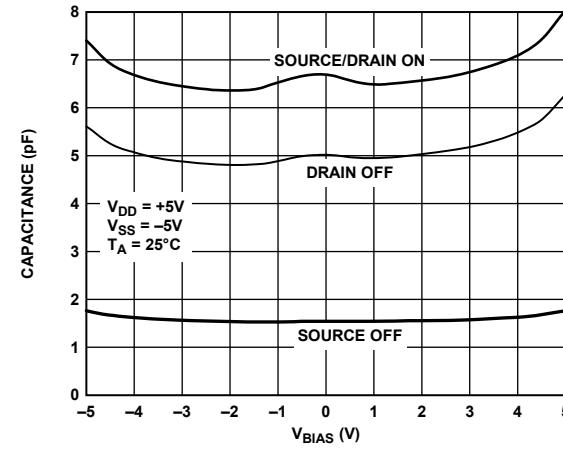


Figure 28. ADG1209 Capacitance vs. Source Voltage, ± 5 V Dual Supply

ADG1208/ADG1209

TERMINOLOGY

R_{ON}

Ohmic resistance between D and S.

ΔR_{ON}

Difference between the R_{ON} of any two channels.

I_s (Off)

Source leakage current when the switch is off.

I_D (Off)

Drain leakage current when the switch is off.

I_D, I_s (On)

Channel leakage current when the switch is on.

V_D (V_S)

Analog voltage on Terminal D, Terminal S.

C_s (Off)

Channel input capacitance for off condition.

C_D (Off)

Channel output capacitance for off condition.

C_D, C_s (On)

On switch capacitance.

C_{IN}

Digital input capacitance.

t_{ON} (EN)

Delay time between the 50% and 90% points of the digital input and switch on condition.

t_{OFF} (EN)

Delay time between the 50% and 90% points of the digital input and switch off condition.

t_{TRANSITION}

Delay time between the 50% and 90% points of the digital inputs and the switch on condition when switching from one address state to another.

T_{BBM}

Off time measured between the 80% point of both switches when switching from one address state to another.

V_{INL}

Maximum input voltage for Logic 0.

V_{INH}

Minimum input voltage for Logic 1.

I_{INL} (I_{INH})

Input current of the digital input.

I_{DD}

Positive supply current.

I_{SS}

Negative supply current.

Off Isolation

A measure of unwanted signal coupling through an off channel.

Charge Injection

A measure of the glitch impulse transferred from the digital input to the analog output during switching.

Bandwidth

The frequency at which the output is attenuated by 3 dB.

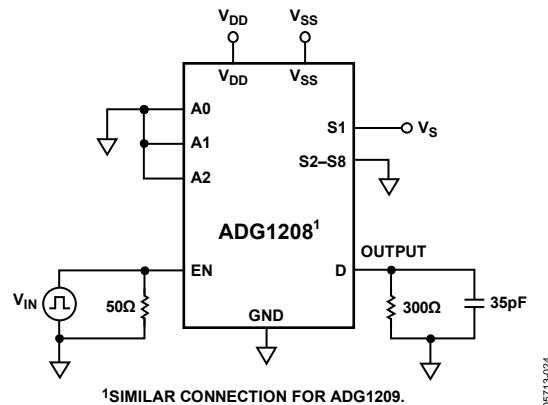
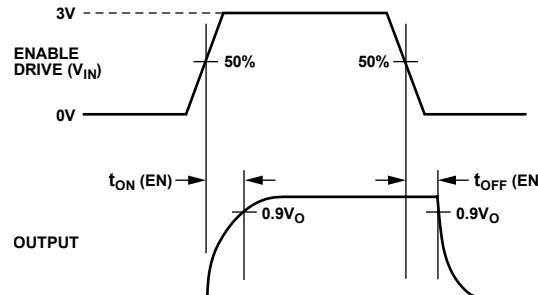
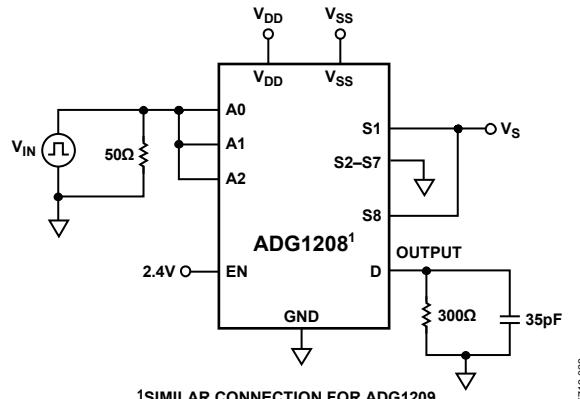
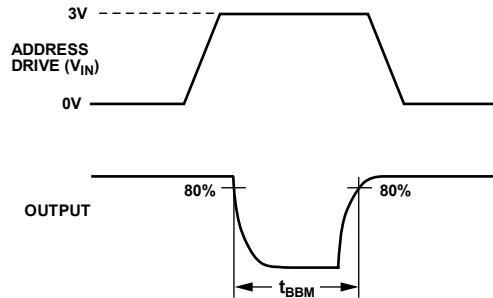
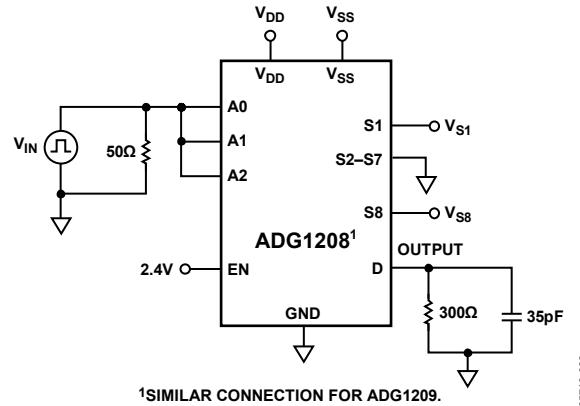
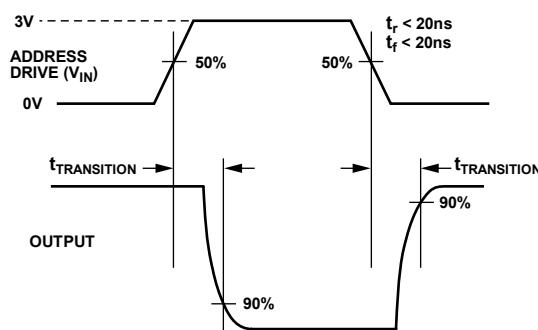
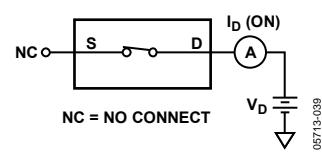
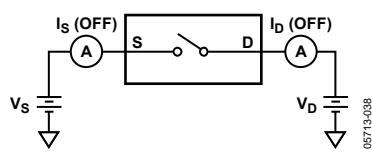
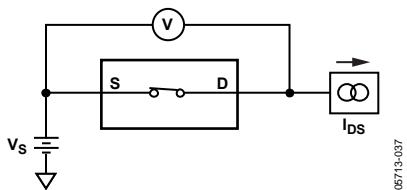
On Response

The frequency response of the on switch.

Total Harmonic Distortion + Noise (THD + N)

The ratio of the harmonic amplitude plus noise of the signal to the fundamental.

TEST CIRCUITS

Figure 34. Enable Delay, $t_{ON} (EN)$, $t_{OFF} (EN)$

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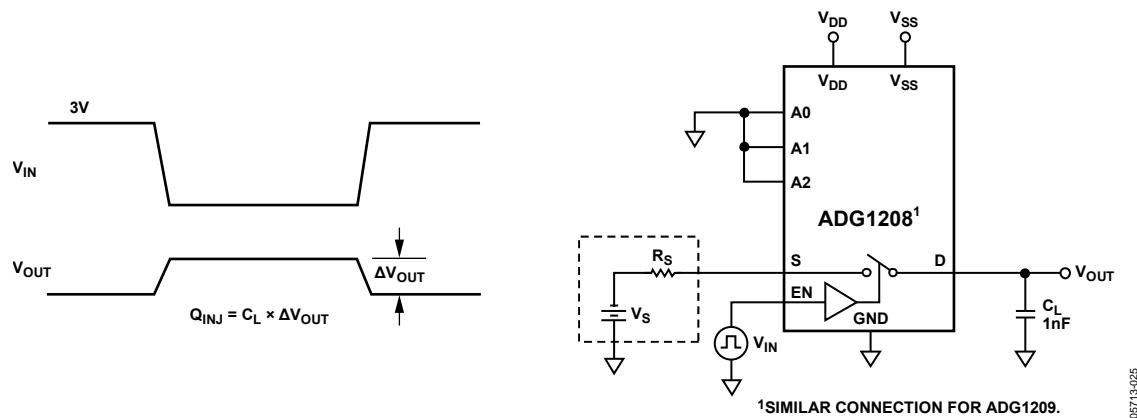


Figure 35. Charge Injection

05713-025

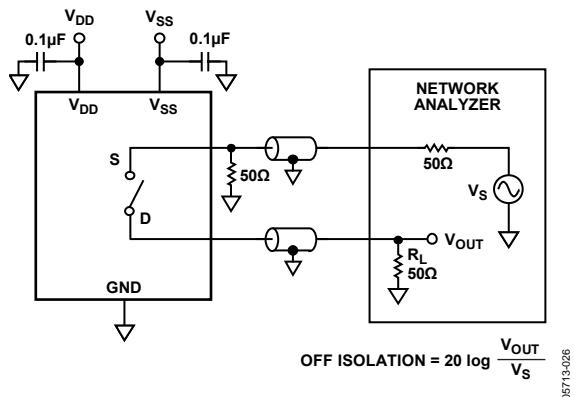


Figure 36. Off Isolation

05713-026

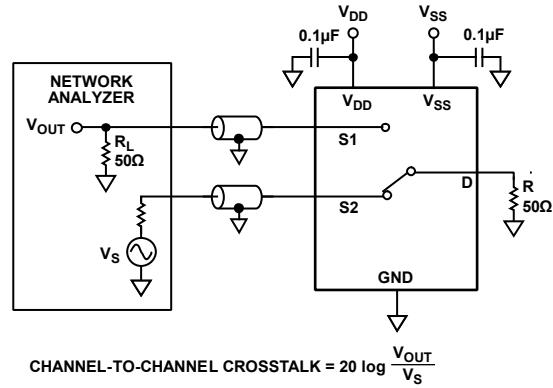


Figure 38. Channel-to-Channel Crosstalk

05713-028

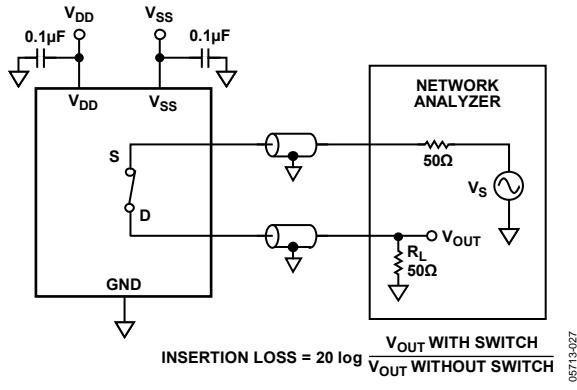


Figure 37. Bandwidth

05713-027

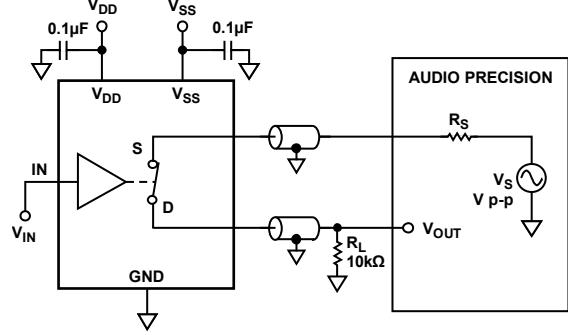
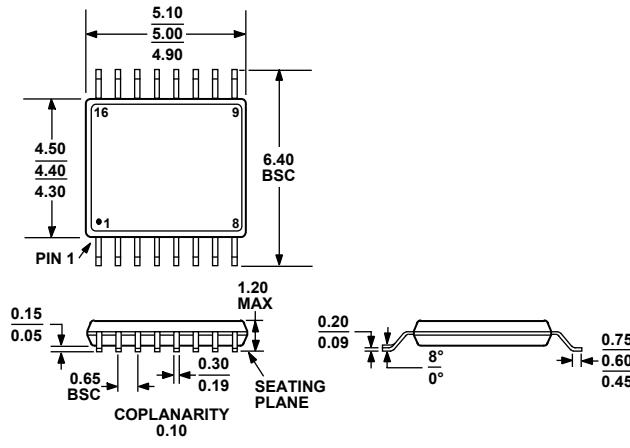


Figure 39. THD + Noise

05713-029

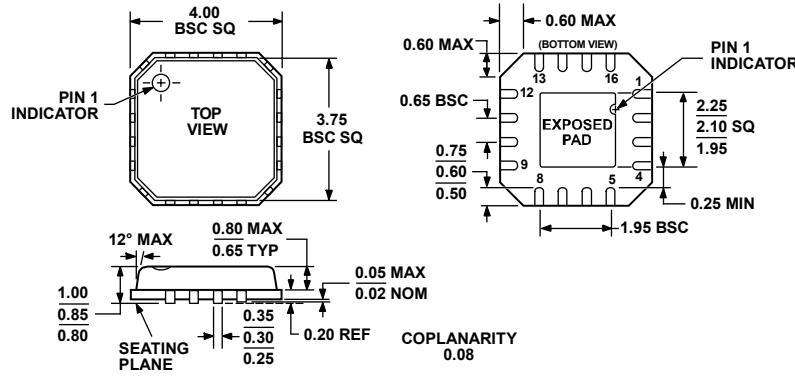
OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-153-AB

Figure 40. 16-Lead Thin Shrink Small Outline Package [TSSOP]
(RU-16)

Dimensions shown in millimeters

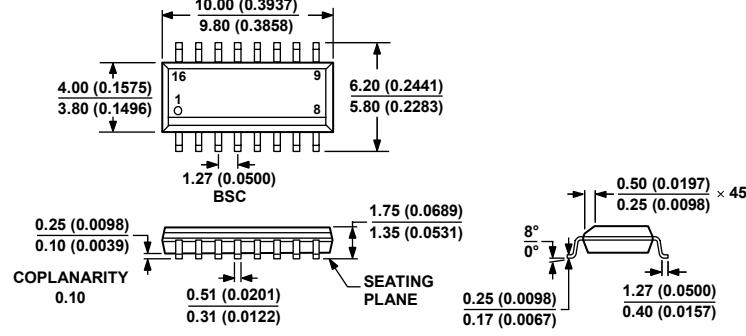


COMPLIANT TO JEDEC STANDARDS MO-220-VGGC

Figure 41. 16-Lead Lead Frame Chip Scale Package [LFCSP_VQ]
4 mm × 4 mm Body, Very Thin Quad (CP-16-4)

Dimensions shown in millimeters

021207-A



COMPLIANT TO JEDEC STANDARDS MS-012-AC

CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

060606-A

Figure 42. 16-Lead Standard Small Outline Package [SOIC_N]

Narrow Body (R-16)

Dimensions shown in millimeters and (inches)

ADG1208/ADG1209

ORDERING GUIDE

| Model | Temperature Range | Package Description | Package Option |
|--------------------------------|-------------------|--|----------------|
| ADG1208YRUZ ¹ | -40°C to +125°C | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16 |
| ADG1208YRUZ-REEL7 ¹ | -40°C to +125°C | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16 |
| ADG1208YCPZ-REEL ¹ | -40°C to +125°C | 16-Lead Lead Frame Chip Scale Package [LFCSP_VQ] | CP-16-4 |
| ADG1208YCPZ-REEL7 ¹ | -40°C to +125°C | 16-Lead Lead Frame Chip Scale Package [LFCSP_VQ] | CP-16-4 |
| ADG1208YRZ ¹ | -40°C to +125°C | 16-Lead Narrow Body Small Outline Package [SOIC_N] | R-16 |
| ADG1208YRZ-REEL7 ¹ | -40°C to +125°C | 16-Lead Narrow Body Small Outline Package [SOIC_N] | R-16 |
| ADG1209YRUZ ¹ | -40°C to +125°C | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16 |
| ADG1209YRUZ-REEL7 ¹ | -40°C to +125°C | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16 |
| ADG1209YCPZ-REEL ¹ | -40°C to +125°C | 16-Lead Lead Frame Chip Scale Package [LFCSP_VQ] | CP-16-4 |
| ADG1209YCPZ-REEL7 ¹ | -40°C to +125°C | 16-Lead Lead Frame Chip Scale Package [LFCSP_VQ] | CP-16-4 |
| ADG1209YRZ ¹ | -40°C to +125°C | 16-Lead Narrow Body Small Outline Package [SOIC_N] | R-16 |
| ADG1209YRZ-REEL7 ¹ | -40°C to +125°C | 16-Lead Narrow Body Small Outline Package [SOIC_N] | R-16 |

¹ Z = RoHS compliant part.

NOTES

ADG1208/ADG1209

NOTES

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D05713-0-4/07(A)



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